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facsimile transmittance

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To:

Examiner Portirio Nazario Gonzalez,

Fax: 703.872.9306

From:

Mag Chappuis

Date:

August 26 2004

E-mail:

Mchappnis@atml.com

Pages:

32

Re:

Response to February 26, 2004 Office Action in U.S. Application Serial No.

cc:

09/954,831

OFFICIAL COMMUNICATION

AMENDMENT RESPONDING TO FEBRUARY 26, 2004 OFFICE ACTION IN U.S. PATENT APPLICATION NO. 09/954,831 AND PETITION FOR EXTENSION OF TIME UNDER 37 C.F.R. § 1.136

Dear Examiner Nazario Gonzalez:

Please find enclosed a Response to the February 26, 2004 Office Action in US Patent Application No. 09/954,831, for Source Reagent Compositions for CVD Formation of Gate Dielectric Thin Films Using Amide Precursors and Method of Using Same, including:

Response – 21 sheets Appendix A – 10 sheets Facsimile Transmittal – 1 sheet

Please call 203-739-1435 if there are any problems with this transmittal.

Maggie Chappnis

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ATMI Docket: ATMI-510 CIP

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